TOSHIBA Photocoupler IRED & Photo-Transistor

TLP624, TLP624-2, TLP624-4

Programmable Controllers AC/DC-Input Module Telecommunication

The TOSHIBA TLP624, -2 and -4 consist of an infrared emitting diode optically coupled to a photo-transistor.

The TLP624-2 offers two isolated channels in an eight lead plastic DIP, while the TLP624-4 provides four isolated channels in a sixteen plastic DIP.

- Collector-emitter voltage: 55 V (min)
- Isolation voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL recognized: CSA Component Acceptance Service No.5A

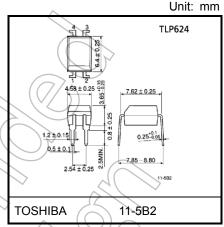
File No.E67349

VDE-approved: EN 60747-5-5 (Note 1)

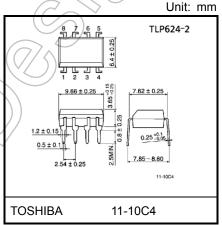
Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

 Note: Application type name for certification test, please use standard product type name, i.e.

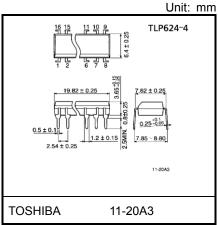
> TLP624(BV): TLP624 TLP624-2(BV): TLP624-2



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)

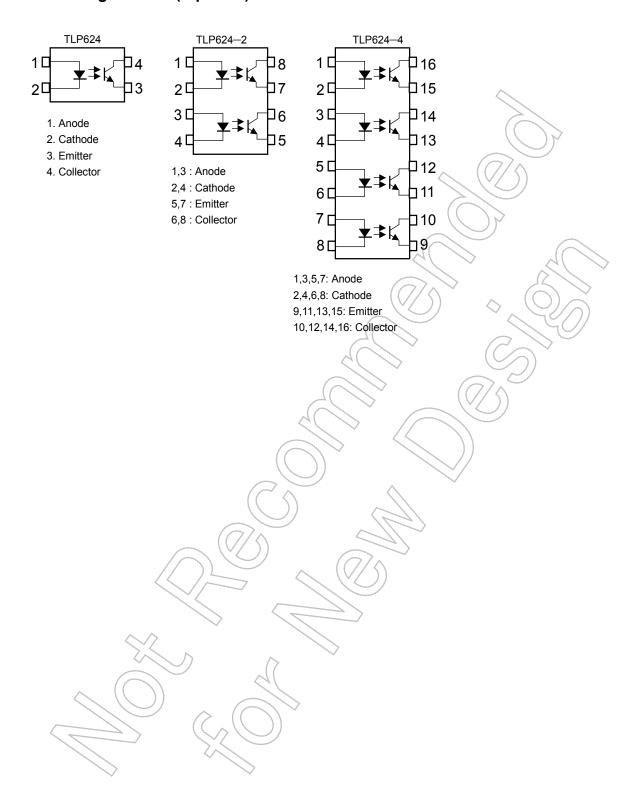


Weight: 1.1 g (typ.)

Classification	Cur	Marking		
	Ta =	25°C	Ta=-25 to 75°C	Marking of
Classification	IF=1mA IF= VCE=0.5V VC		I _F =1mA V _{CE} =0.5V	classification
Rank BV	200%	100%	100%	BV
Standard	100%	50%	50%	BV, blank

Start of commercial production 1986-04

Pin Configurations (top view)



Absolute Maximum Ratings (Ta = 25°C)

				Rat	ting	
	Characteristic		Symbol	TLP624 TLP624-2 TLP624-4		Unit
	Forward current		lF	60	50	mA
	Forward current detating		ΔI _F / °C	-0.7(Ta ≥ 39°C)	-0.5(Ta ≥ 25°C)	mA / °C
	Pulse forward current			1 (100μs, pu	lse, 100pps)	Α
LED	Diode Power dissipation		PD	100	70	mW
	Diode Power dissipation derating		ΔP _D / °C	-1.2(Ta ≥ 39°C)	-0.7(Ta ≥ 25°C)	mW / °C
	Reverse voltage		V _R	((//))	5	V
	Junction temperature		Tj	12	25	°C
	Collector-emitter voltage		V _{CEO}	5	55	V
	Emitter-collector voltage		VECØ		7	V
ctor	Collector current		16	5	0 10	mA
Detector	Collector power dissipation (1 circuit)		PG	150	100	mW
	Collector power dissipation derating (Ta ≥ 25°C, 1 circ	cuit)	ΔPc/°C	-1.5	21.0	mW / °C
	Junction temperature)	Tj	15	25	°C
Stor	age temperature range		T _{stg}	-55 to	o 125	°C
Ope	rating temperature range		Popr	-55 ts	100	°C
Lead	d soldering temperature		T _{sol}	260 ((10 s)	°C
Tota	ll package power dissipation (1 circuit)		PT	250	150	mW
Tota	ll package power dissipation derating (Ta ≥ 25°C, 1 cir	cuit)	ΔPτ / °C	-2.5	-1.5	mW / °C
Isola	ation voltage	(Note 1)	BVs	5000 (AC, 60	s, R.H.≤60 %)	Vrms
				J /		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins shorted together, and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	V
Forward current	₩F	_	1.6	20	mA
Collector current	lc	_	1	10	mA
Operating temperature	Topr	-25	_	75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

© 2019 3 2019-06-24

Electrical Characteristics (Ta = 25°C)

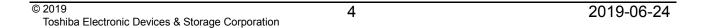
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	CT	V = 0 V, f = 1 MHz	-<	30	-	pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55			V
o	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1 mA	7		<u> </u>	V
Detector	Collector dark current	lono	V _{CE} = 24 V	(7)	10	100	nA
ă	Collector dark current	ICEO	V _{CE} = 24 V, Ta = 85 °C) 2	50	μΑ
	Capacitance collector to emitter	CCE	V = 0 V, f = 1 MHz		12	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	I _C / I _F	I _F = 1 mA, V _{CE} = 0.5 V Rank BV	100	ME	1200 1200	%
Low input CTR	IC / IF (low)	$I_F = 0.5$ mA, $V_{CE} = 1.5$ V Rank BV	50 100)		%
		Ic = 0.5 mA, IF = 1 mA	(%)	_	0.4	
Collector-emitter saturation voltage	VCE (sat)	I _C = 1 mA, I _F = 1 mA)	0.2	_	V
		Rank BV	\)-	_	0.4	

Coupled Electrical Characteristics (Ta = -25°C to 75°C)

Character	ristic	Symbol	Test Condit	ion	Min	Тур.	Max	Unit
Current transfer ratio		JC / IF	I _F = 1 mA, V _{CE} = 0	5 V	50	_	_	%
Current transfer ratio	//)	JC/ IF	((//	Rank BV	100	-	_	70
Low input CTP		/ lo/le#	I _F = 0.5 mA, V _{CE} =	1.5 V	_	50	_	%
Low input CTR		IC / IF (low)		Rank BV	_	100	_	/0



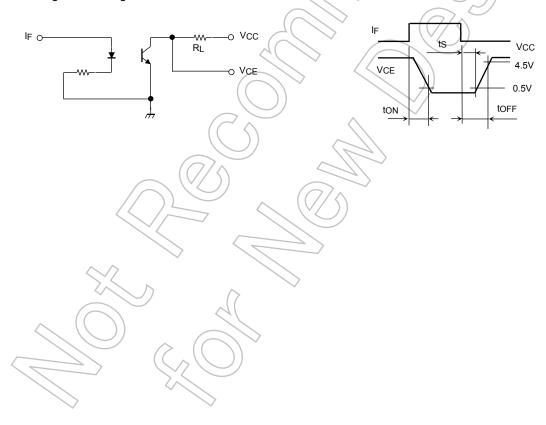
Isolation Characteristics (Ta = 25°C)

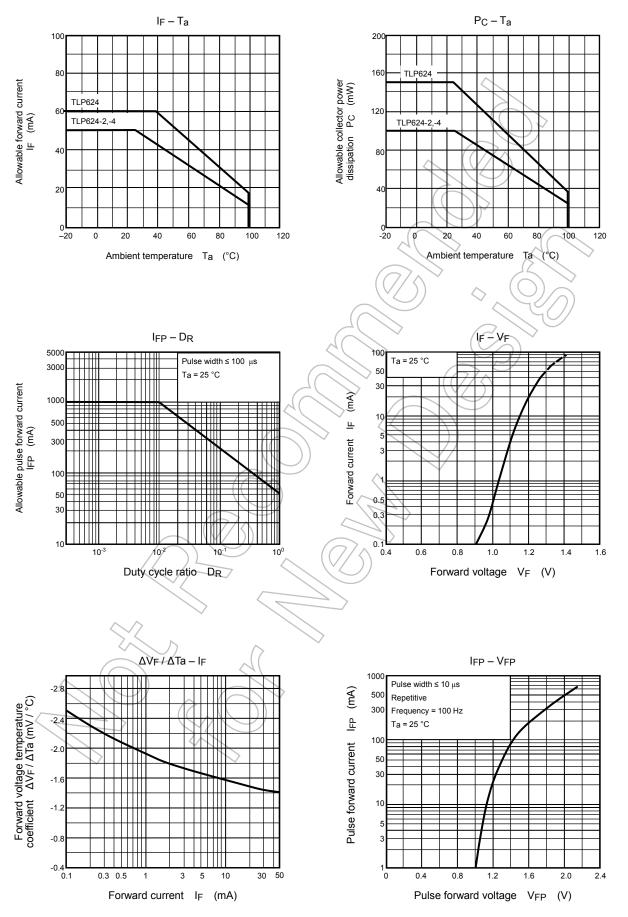
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	_	_	Vrms

Switching Characteristics (Ta = 25°C)

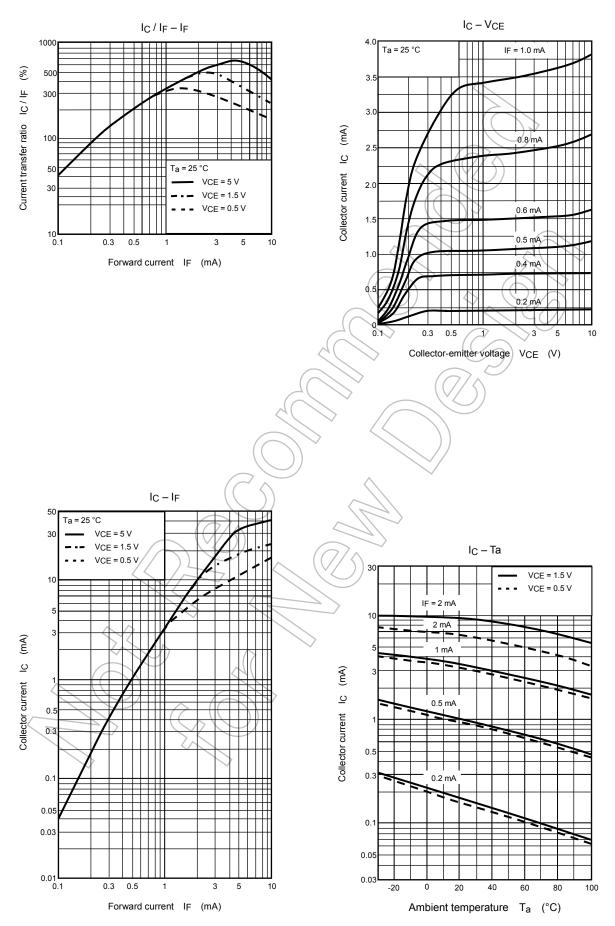
Characteristic	Symbol	Test Condition	Min Typ.	Max	Unit
Rise time	t _r		8	_	
Fall time	t _f	V_{CC} = 10 V, I_C = 2 mA R_L = 100 Ω	8	_	0
Turn-on time	ton		_ 10		μS
Turn-off time	toff		_ 8	1	\searrow
Turn-on time	toN	(7/6)	_ 10	7	
Storage time	ts	R _L = 4.7 k Ω (Fig.1) V _{CC} = 5 V, I _F = 1.6 mA	50	$(\mathcal{I}_{\mathcal{I}})$	μS
Turn-off time	toff		_ 300		

Fig. 1 Switching time test circuit

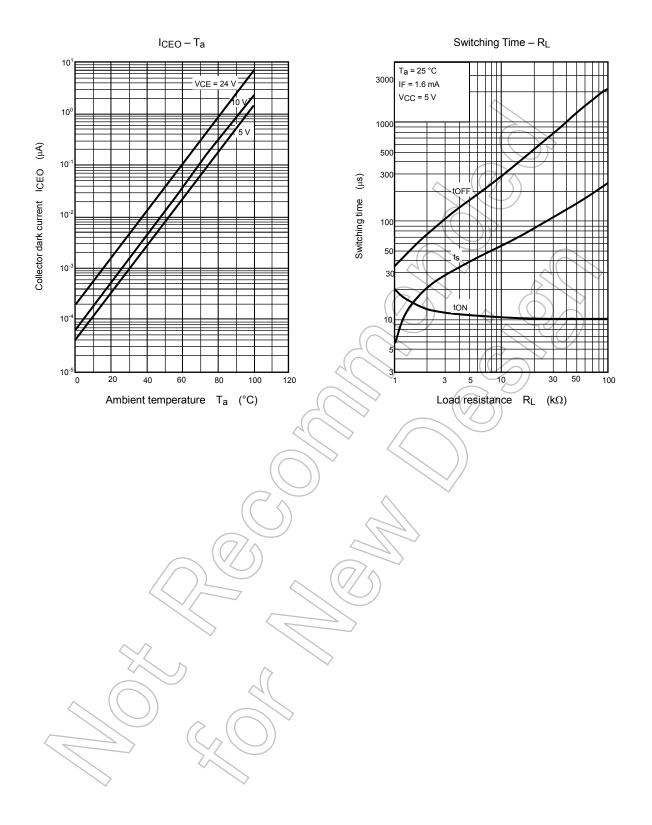




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
 equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to
 control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
 Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
 substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/